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Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)				Complete if Known	
Sheet	1	of	1		
				Application Number	10/787,310
				Filing Date	February 26, 2004
				First Named Inventor	Robert F. Steinle et al.
				Group Art Unit	2812
				Examiner Name	Unknown
				Attorney Docket Number	SC191930TP

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
PJH	BB	KIM, Dong-Won et al.; "Charge retention characteristics of SiGe quantum dot flash memories"; Conference Digest of 60 th Device Research Conference; 2002; 1 pg abstract & pp151-152; IEEE; USA.	
b	BC	ZHU, Jane G. et al; "Effects of Ion Beam Mixing on the Formation of SiGe Nanocrystals by Ion Implantation"; Proceedings of the 11 th International Conference of Ion Implantation Technology; June 16-21, 1996; 1 pg abstract & pp 690-693; IEEE; USA.	

Examiner Signature	Burkean	Date Considered	04/15/05
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EXAMINER: Initial U references considered, whether or not cited is in conformance with MPEP 608. Draw line through citation, if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Unique citation designation number. ² Applicant is to place a check mark here if English Language Translation is attached.